

Code: CE1T3, CS1T3, EC1T4, IT1T3

**I B. Tech - I Semester – Regular/Supplementary Examinations  
December 2016**

**ENGINEERING CHEMISTRY  
(Common for CE, CSE, ECE & IT)**

Duration: 3 hours

Max. Marks: 70

**PART – A**

Answer *all* the questions. All questions carry equal marks

11 x 2 = 22 M

1.

- a) State the impurities that cause hardness of water.
- b) Why is hot lime-soda process better than the cold process?
- c) Give any two examples of biodegradable polymers.
- d) Mention the moulding constituents of plastics.
- e) What is sonochemistry? Explain.
- f) Explain any two engineering applications of fullerenes.
- g) Write a short note on dry corrosion.
- h) What are the characteristics of a good paint?
- i) Discuss briefly on Superconductors.
- j) Give any four applications of liquid crystals.
- k) What is Doping? Explain with one example.

**PART – B**

Answer any *THREE* questions. All questions carry equal marks.

3 x 16 = 48 M

2. a) Calculate the temporary and permanent hardness water containing  $\text{Mg}(\text{HCO}_3)_2=29.2\text{mg/L}$ ,  $\text{Ca}(\text{HCO}_3)_2= 32.4\text{mg/L}$ ,  $\text{CaCl}_2 =27.75\text{mg/L}$ ,  $\text{MgSO}_4=24\text{mg/L}$ ,  $\text{KCl}=20\text{mg/L}$ . 6 M

- b) Distinguish between hot lime-soda and cold lime-soda process. 4 M
- c) Illustrate the reverse osmosis process with a diagram. 6 M
3. a) Enumerate the differences between addition and condensation polymerization. 4 M
- b) Write a brief note on the preparation and properties of Bakelite. 6 M
- c) Describe any two moulding techniques for fabrication of plastics. 6 M
4. a) Write the principles of green chemistry. 8 M
- b) What are carbon nanotubes? Explain their types. 8 M
5. a) Discuss the mechanism of electrochemical corrosion. 4 M
- b) Write notes on
- i) Differential aeration 4 M
  - ii) Sacrificial anodic protection 4 M
  - iii) Galvanizing 4 M
6. a) Explain the stoichiometric and non-stoichiometric defects in crystals. 8 M
- b) Write a detailed note on liquid crystal display. 4 M
- c) Write a brief account on photo voltaic cells. 4 M